

	Type	Hits	Search Text
1	BRS	768	(semiconductor near laser) and (active near (layer or region or medium or film)) and (quantum near well or qw) and (mirror or ((low and high) near reflect\$)) and 372/\$
2	BRS	260	((semiconductor near laser) and (active near (layer or region or medium or film)) and (quantum near well or qw) and (mirror or ((low and high) near reflect\$)) and 372/\$) and 372/96
3	BRS	11	(((semiconductor near laser) and (active near (layer or region or medium or film)) and (quantum near well or qw) and (mirror or ((low and high) near reflect\$)) and 372/\$) and 372/96) and (laminat\$ near structure)
4	BRS	4	(semiconductor near laser) and (active near (layer or region or medium or film)) and (quantum near well or qw) and ((low and high) near reflect\$) and 372/\$ and (laminat\$ near structure)
5	BRS	4	((semiconductor near laser) and (active near (layer or region or medium or film)) SAME (quantum near well or qw) and ((low and high) near reflect\$) and (laminat\$ near structure)) and 372/\$

	DBs	Time Stamp	Comments	Error Definition	Errors
1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/11/29 18:06		Truncation Overflow. Return string from Server is: 5`1069902	1
2	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/11/29 18:04			0
3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/11/29 18:05			0
4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/11/29 18:11		Truncation Overflow. Return string from Server is: 5`1069902	1
5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/11/29 18:19			0

	Type	Hits	Search Text
6	BRS	5	(semiconductor near laser) and (active near (layer or region or medium or film) SAME (quantum near well or qw)) and ((low and high) near reflect\$) and (laminat\$ near structure)
7	BRS	73	(semiconductor near laser) and (active near (layer or region or medium or film) SAME (quantum near well or qw)) and ((low and high) near reflect\$)
8	BRS	1	(semiconductor near laser) and (active near (layer or region or medium or film) SAME (quantum near well or qw)) and ((low and high) near mirror) and (laminat\$ near structure)
9	BRS	56	((semiconductor near laser) and (active near (layer or region or medium or film) SAME (quantum near well or qw)) and ((low and high) near reflect\$)) and 372/\$
10	BRS	4	(semiconductor near laser) and (active near (layer or region or medium or film) SAME (quantum near well or qw)) and ((low and high) near mirror)

	DBs	Time Stamp	Comments	Error Definition	Errors
6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/11/29 19:24		Truncation Overflow. Return string from Server is: 5`1069902	1
7	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/11/29 19:27		Truncation Overflow. Return string from Server is: 5`1069902	1
8	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/11/29 19:27			0
9	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/11/29 19:28			0
10	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/11/29 19:42			0